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# VS-VSKD600..PbF

**Vishay Semiconductors** 

# Standard Diodes (Super MAGN-A-PAK Power Modules), 600 A



Super MAGN-A-PAK

### FEATURES

- High current capability
- High surge capability
- High voltage ratings up to 2000 V
- $\bullet$  3000  $V_{\text{RMS}}$  isolating voltage with non-toxic substrate
- Industrial standard package
- UL approved file E78996
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

#### **TYPICAL APPLICATIONS**

- Rectifying bridge for large motor drives
- Rectifying bridge for large UPS

PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub>	600 A				
Туре	Modules - diode, high voltage				
Package	Super MAGN-A-PAK				
Circuit configuration	Two diodes doubler circuit				

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
		600	A		
I <sub>F(AV)</sub>	T <sub>C</sub>	100	°C		
1		942	A		
I <sub>F</sub> (RMS)	T <sub>C</sub>	100	°C		
IFSM	50 Hz	19 000	•		
	60 Hz	20 100	— A		
l <sup>2</sup> t	50 Hz	1805	– kA <sup>2</sup> s		
1-1	60 Hz	1683	KA-S		
l²√t		18 050	kA²√s		
V <sub>RRM</sub>	Range	800 to 2000	V		
T <sub>Stg</sub> , T <sub>J</sub>	Range	-40 to +150	°C		

### **ELECTRICAL SPECIFICATIONS**

VOLTAGE RATINGS								
TYPE NUMBER	VOLTAGE CODE	V <sub>RRM</sub> , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I <sub>RRM</sub> MAXIMUM AT T <sub>J</sub> MAXIMUM mA				
	08	800	900					
VS-VSKD600	12	1200	1300	50				
V3-V3ND000	16	1600	1700	50				
	20	2000	2100					

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FORWARD CONDUCTION						
PARAMETER	SYMBOL	TEST CONDITIONS			VALUES	UNITS
Maximum average forward current		180° conduction, half sine wave			600	А
at case temperature	I <sub>F(AV)</sub>		uction, nan sine	e wave	100	°C
Maximum RMS forward current	I <sub>F(RMS)</sub>	180° condu	uction, half sine	e wave at T <sub>C</sub> = 100 °C	942	А
		t = 10 ms	No voltage		19.0	
Maximum peak, one-cycle forward,	l	t = 8.3 ms	reapplied		20.1	kA
non-repetitive surge current	IFSM	t = 10 ms	100 % V <sub>RRM</sub>	Sinusoidal half wave, initial $T_J = T_J$ maximum	16.2	
		t = 8.3 ms	reapplied		17.2	
	l <sup>2</sup> t	t = 10 ms	No voltage		1805	- kA <sup>2</sup> s
Movimum 12t for fusing		t = 8.3 ms	reapplied		1683	
Maximum I <sup>2</sup> t for fusing		t = 10 ms	100 % V <sub>RRM</sub>		1319	
		t = 8.3 ms	reapplied		1230	
Maximum I <sup>2</sup> √t for fusing	l²√t	t = 0.1 ms	to 10 ms, no vo	oltage reapplied	18 050	kA²√s
Low level value of threshold voltage	V <sub>F(TO)1</sub>	$(16.7 \% x \pi x I_{F(AV)} < I < \pi x I_{F(AV)}), T_J = T_J maximum$			0.70	v
High level value of threshold voltage	V <sub>F(TO)2</sub>	$(I > \pi x I_{F(AV)}), T_J = T_J maximum$			0.77	v
Low level value of forward slope resistance	r <sub>f1</sub>	$(16.7 \% x \pi x I_{F(AV)} < I < \pi x I_{F(AV)}), T_J = T_J \text{ maximum}$			0.28	
High level value of forward slope resistance	r <sub>f2</sub>	$(I > \pi \times I_{F(AV)}), T_J = T_J \text{ maximum}$ 0.2			0.25	mΩ
Maximum forward voltage drop	V <sub>FM</sub>	I <sub>pk</sub> = 1800	A, T <sub>J</sub> = 25 °C, t	<sub>p</sub> = 10 ms sine pulse	1.45	V

BLOCKING					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
RMS insulation voltage	V <sub>INS</sub>	t = 1 s	3000	V	
Maximum peak reverse and off-state leakage current	I <sub>RRM</sub>	$T_J = T_J$ maximum, rated $V_{RRM}$ applied	50	mA	

THERMAL AND MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction operating and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-40 to +150	°C		
Maximum thermal resistance, junction to case per junction	R <sub>thJC</sub>	DC operation	0.065	K/W		
Maximum thermal resistance, case to heatsink per module	R <sub>thC-hs</sub>	Mounting surface smooth, flat and greased	0.02	r∕ vv		
Mounting Super MAGN-A-PAK to heatsink		A mounting compound is recommended and the	6 to 8			
torque ± 10 % busbar to Super MAGN-A-PAK		torque should be rechecked after a period of 3 hours to allow for the spread of the compound	12 to 15	Nm		
Approximate weight			1500	g		
Case style		See dimensions - link at the end of datasheet Super MA		I-A-PAK		

	N			
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS
180°	0.009	0.006		
120°	0.011	0.011		
90°	0.014	0.015	$T_J = T_J$ maximum	K/W
60°	0.021	0.022		
30°	0.037	0.038		

Note

• The table above shows the increment of thermal resistance RthJC when devices operate at different conduction angles than DC

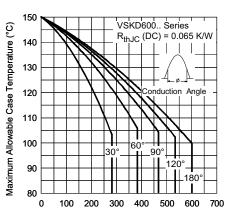
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 2
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Average Forward Current (A)

Fig. 1 - Current Ratings Characteristics

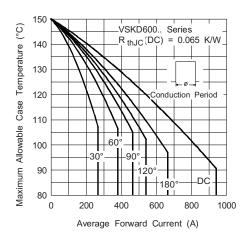


Fig. 2 - Current Ratings Characteristics

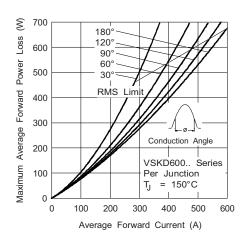


Fig. 3 - Forward Power Loss Characteristics

§ 1000 DC Loss 900 180 120 800 Maximum Average Forward Power 90 60 700 30 600 500 RMS 400 Conduction Period 300 VSKD600.. Series 200 Per Junction 100 = 150°C ТJ 0 0 200 400 600 800 1000 Average Forward Current (A)

Fig. 4 - Forward Power Loss Characteristics

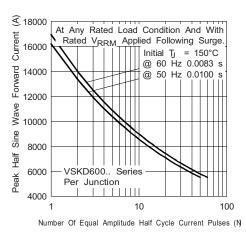


Fig. 5 - Maximum Non-Repetitive Surge Current

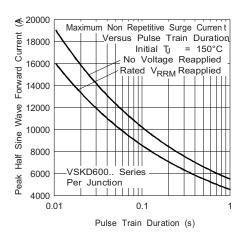


Fig. 6 - Maximum Non-Repetitive Surge Current

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 Revision: 09-Jan-2025
 3
 Document Number: 93583

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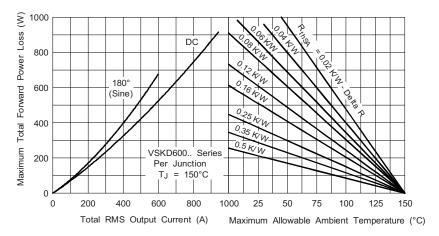


Fig. 7 - Forward Power Loss Characteristics

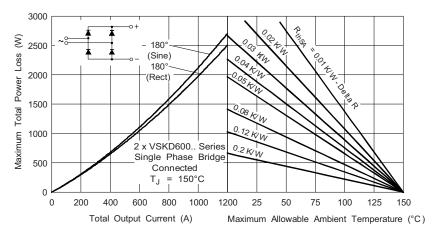


Fig. 8 - Forward Power Loss Characteristics

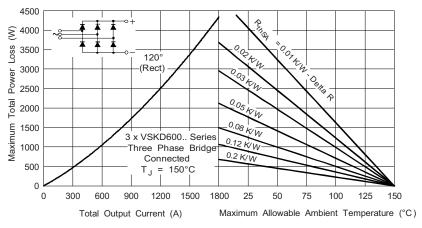


Fig. 9 - Forward Power Loss Characteristics

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 4
 Document Number: 93583

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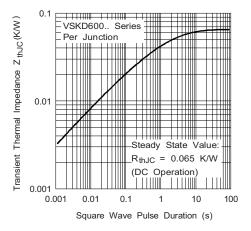


Fig. 10 - Thermal Impedance Z<sub>thJC</sub> Characteristic

### **ORDERING INFORMATION TABLE**

Device code	VS-VS	KD	600	-	20	PbF	
		2	3		4	5	
	1 - 2 -	Circ	cuit conf	niconduo iguratio configu	n D = tv	vo diod	es in series
	<ul> <li>Gurrent rating</li> <li>Voltage code x 100 = V<sub>RRM</sub> (see voltage ratings</li> <li>Lead (Pb)-free</li> </ul>					oltage ratings table)	

CIRCUIT CONFIGURATION					
CIRCUIT DESCRIPTION	CIRCUIT CONFIGURATION CODE	CIRCUIT DRAWING			
Two diodes doubler circuit	KD				

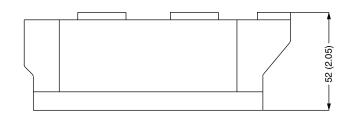
LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95088			

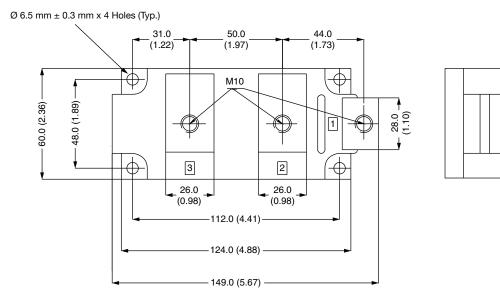


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# Super MAGN-A-PAK Diode

### **DIMENSIONS** in millimeters (inches)





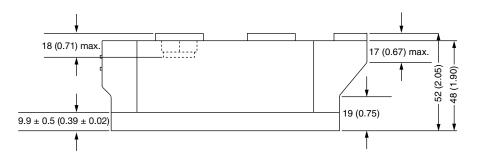
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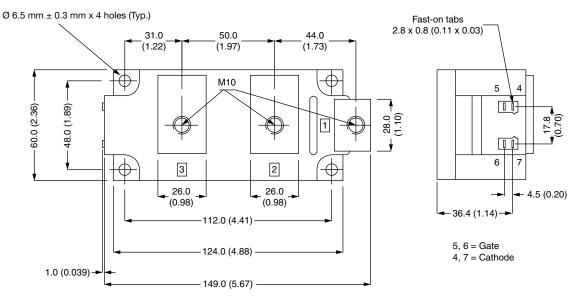


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# Super MAGN-A-PAK Thyristor/Diode

### **DIMENSIONS** in millimeters (inches)







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1